

Substitute for form 1449A/PTO

INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT

(Use as many sheets as necessary)

Complete if Known

Application Number	Unknown
Filing Date	Even Date Herewith
First Named Inventor	Moradi, Behnam
Group Art Unit	Unknown
Examiner Name	Ramsey, Kenneth

Sheet 1 of 2

Attorney Docket No: 303.591US2

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Plenn M Zimmerman

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6/2/04

Substitute Disclosure Statement Form (PTO-1440)

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 608. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. 1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.

K Suharay 4/5/07

<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> <small>(Use as many sheets as necessary)</small>		Complete if Known	
		<b>Application Number</b>	Unknown
		<b>Filing Date</b>	Even Date Herewith
		<b>First Named Inventor</b>	Moradi, Behnam
		<b>Group Art Unit</b>	Unknown
		<b>Examiner Name</b>	Ramsey, Kenneth
Sheet 2 of 2		Attorney Docket No: 303.591US2	

OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS			
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